

2MBI1800XXF170-50

IGBT Modules

Power Module (X series)
1700V / 1800A / 2-in-1 package

■ Features

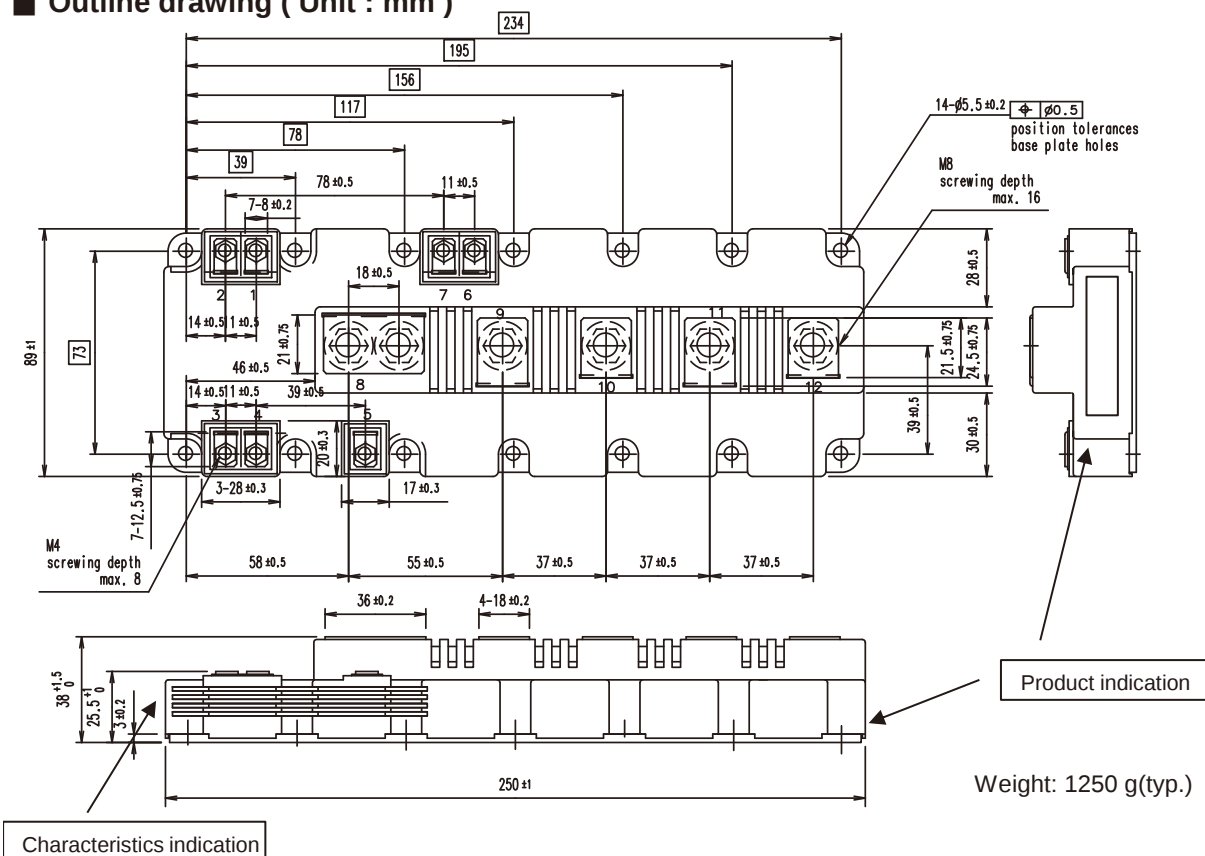
- Low $V_{CE(sat)}$
- Low Inductance Module structure

■ Applications

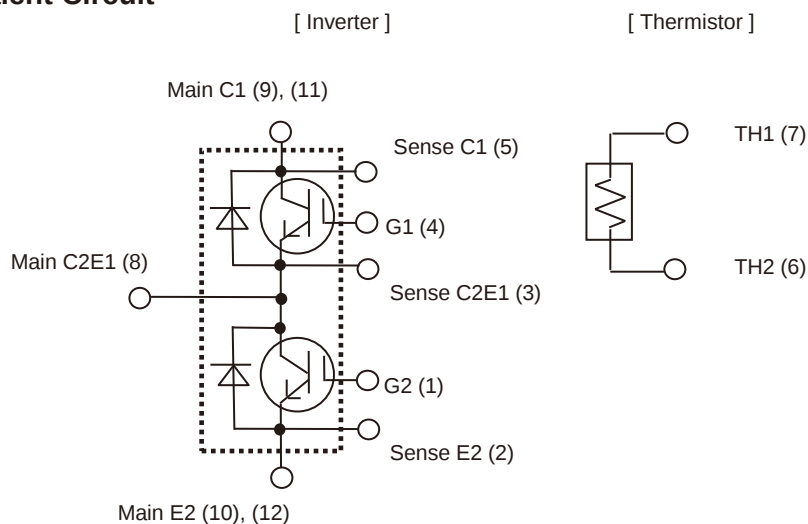
- Inverter for Motor Drives, AC and DC Servo Drives
- Uninterruptible Power Supply Systems, Wind Turbines, PV Power Conditioning Systems



■ Outline drawing (Unit : mm)



■ Equivalent Circuit



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■ Absolute Maximum Ratings (at $T_c = 25^\circ\text{C}$ unless otherwise specified)

Items		Symbols	Conditions		Maximum Ratings	Units
Inverter	Collector-Emitter voltage, Gate-Emitter short-circuited	V_{CES}			1700	V
	Gate-Emitter voltage, Collector-Emitter short-circuited	V_{GES}			±20	V
	Collector current	I_C	Continuous	$T_C=100^{\circ}\text{C}$	1800	A
	Repetitive peak collector current	I_{CRM}	1ms		3600	
	Forward current	I_F			1800	
	Repetitive peak forward current	I_{FRM}	1ms		3600	
	Total power dissipation	P_{tot}	1 device		13	kW
	Virtual junction temperature	T_{vj}			175	$^{\circ}\text{C}$
	Operating virtual junction temperature (under switching conditions)	T_{vjop}			175	
	Case temperature	T_c			150	
	Storage temperature	T_{stg}			-40 ~ 150	
	Isolation voltage	between terminal and copper base (*1) between thermistor and others (*2)	V_{isol}	AC: 1min.		4000
Mounting torque of screws to heatsink (*3)		M_s	M5		6.0	N·m
Mounting torque of screws to main terminals (*3)		M_t	M8		10.0	
Mounting torque of screws to sense terminals (*3)			M4		2.1	

(*1) All terminals should be connected together during the test.

(*2) Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

(*3) Recommendable Value: : Mounting torque of screws to heatsink 3.0 ~ 6.0 N·m (M5)
 : Mounting torque of screws to main terminals 8.0~ 10.0 N·m (M8)
 : Mounting torque of screws to sense terminals 1.8~ 2.1 N·m (M4)

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■ Electrical characteristics (at $T_{vj}=25^{\circ}\text{C}$ unless otherwise specified)

Items		Symbols	Conditions		Characteristics			Units
					min.	typ.	max.	
Inverter	Collector-Emitter cut-off current, Gate-Emitter short-circuited	I_{CES}	$V_{GE} = 0V$ $V_{CE} = 1700V$		-	-	600	μA
	Gate leakage current, Collector-Emitter short-circuited	I_{GES}	$V_{CE}=0V, V_{GE}=\pm 20V$		-	-	1200	nA
	Gate-Emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = 20V$ $I_C = 1800mA$		6.0	6.5	7.0	V
	Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15V$ $I_C = 1800A$	$T_{vj}=25^{\circ}C$	-	1.75	2.20	V
		$V_{CE(sat)}$ (chip)		$T_{vj}=25^{\circ}C$	-	1.70	2.15	
				$T_{vj}=125^{\circ}C$	-	2.10	-	
				$T_{vj}=150^{\circ}C$	-	2.20	-	
				$T_{vj}=175^{\circ}C$	-	2.30	-	
	Internal gate resistance	r_g	-		-	2.08	-	Ω
	Capacitance	C_{ies}	$V_{CE}=10V, V_{GE}=0V, f=1MHz$		-	280	-	nF
		C_{oes}			-	7.3	-	
		C_{res}			-	2.2	-	
	Gate charge	Q_G	$V_{CC} = 900V, I_C = 1800A$ $V_{GE} = -15 \rightarrow +15V$		-	14.3	-	μC
	Forward voltage	V_F (terminal)	$V_{GE} = 0V$ $I_F= 1800A$	$T_{vj}=25^{\circ}C$	-	1.80	2.25	V
		V_F (chip)		$T_{vj}= 25^{\circ}C$	-	1.75	2.20	
				$T_{vj}=125^{\circ}C$	-	1.95	-	
				$T_{vj}=150^{\circ}C$	-	1.95	-	
				$T_{vj}=175^{\circ}C$	-	1.90	-	
	Switching time (*1)	$t_{d(on)}$	$V_{CC} = 900V$ $I_C, I_F = 1800A$ $V_{GE} = \pm 15 V$ $R_G = +0.22/-0.68\Omega$ $L_S = 40 nH$	$T_{vj}= 25^{\circ}C$	-	1.11	-	μs
				$T_{vj}=125^{\circ}C$	-	1.09	-	
$T_{vj}=150^{\circ}C$				-	1.09	-		
$T_{vj}=175^{\circ}C$				-	1.09	-		
t_r		$T_{vj}= 25^{\circ}C$		-	0.16	-		
		$T_{vj}=125^{\circ}C$		-	0.18	-		
		$T_{vj}=150^{\circ}C$		-	0.18	-		
		$T_{vj}=175^{\circ}C$		-	0.18	-		
$t_{d(off)}$		$T_{vj}= 25^{\circ}C$		-	1.02	-		
		$T_{vj}=125^{\circ}C$		-	1.07	-		
		$T_{vj}=150^{\circ}C$		-	1.09	-		
		$T_{vj}=175^{\circ}C$		-	1.10	-		
t_f		$T_{vj}= 25^{\circ}C$		-	0.20	-		
		$T_{vj}=125^{\circ}C$		-	0.44	-		
		$T_{vj}=150^{\circ}C$		-	0.50	-		
		$T_{vj}=175^{\circ}C$		-	0.56	-		
Reverse recovery time	t_{rr}	$T_{vj}= 25^{\circ}C$		-	0.38	-		
		$T_{vj}=125^{\circ}C$		-	0.52	-		
		$T_{vj}=150^{\circ}C$		-	0.56	-		
		$T_{vj}=175^{\circ}C$		-	0.60	-		

(*1) Turn on time (t_{on}) = $t_{d(on)} + t_r$, Turn off time (t_{off}) = $t_{d(off)} + t_f$

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■ Electrical characteristics (at $T_{vj}=25^{\circ}\text{C}$ unless otherwise specified)

Items		Symbols	Conditions		Characteristics			Units
					min.	typ.	max.	
Inverter	Switching loss (per pulse)	E_{on}	$V_{CC} = 900V$ $I_C, I_F = 1800A$ $V_{GE} = \pm 15 V$ $R_G = +0.22/-0.68\Omega$ $L_S = 40\text{ nH}$	$T_{vj}=25^{\circ}C$	-	424	-	mJ
				$T_{vj}=125^{\circ}C$	-	540	-	
				$T_{vj}=150^{\circ}C$	-	574	-	
				$T_{vj}=175^{\circ}C$	-	612	-	
		E_{off}	$T_{vj}=25^{\circ}C$	-	459	-		
			$T_{vj}=125^{\circ}C$	-	585	-		
			$T_{vj}=150^{\circ}C$	-	621	-		
			$T_{vj}=175^{\circ}C$	-	651	-		
		E_{rr}	$T_{vj}=25^{\circ}C$	-	284	-		
			$T_{vj}=125^{\circ}C$	-	410	-		
			$T_{vj}=150^{\circ}C$	-	464	-		
			$T_{vj}=175^{\circ}C$	-	517	-		
Thermistor	Resistance	R	$T =$	25°C	-	5000	-	Ω
			$T =$	100°C	465	495	520	
	B value	B	$T =$	25/ 50°C	3305	3375	3450	K

NOTICE:

The external gate resistance (R_G) shown above is one of our recommended value for the purpose of minimum switching loss. However the optimum R_G depends on circuit configuration and/or environment. We recommend that the R_G has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

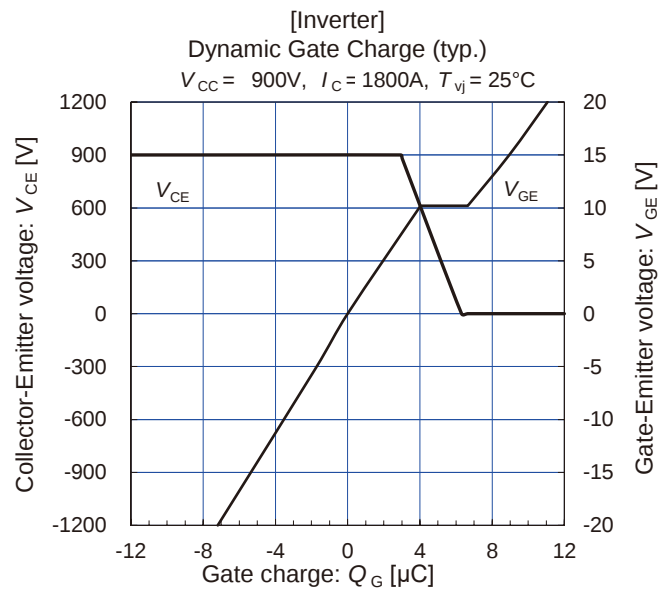
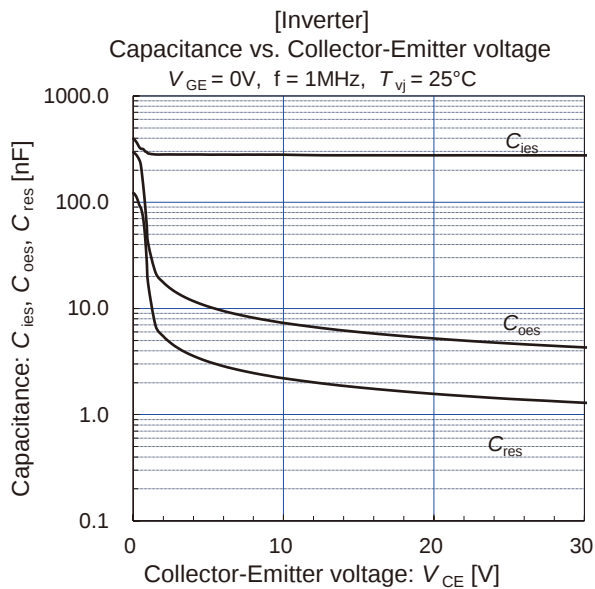
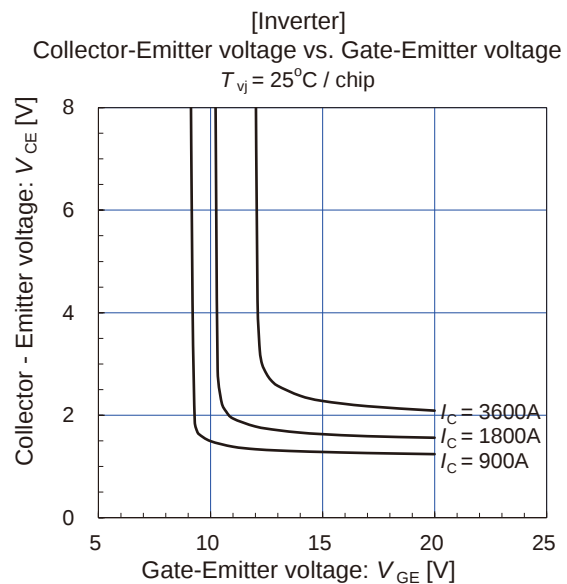
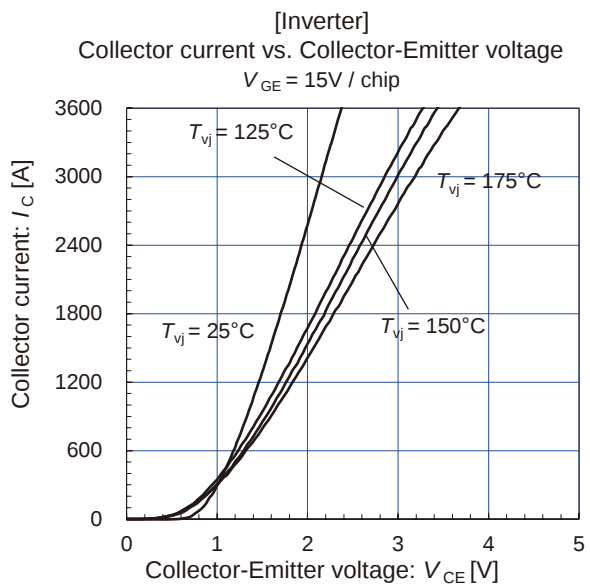
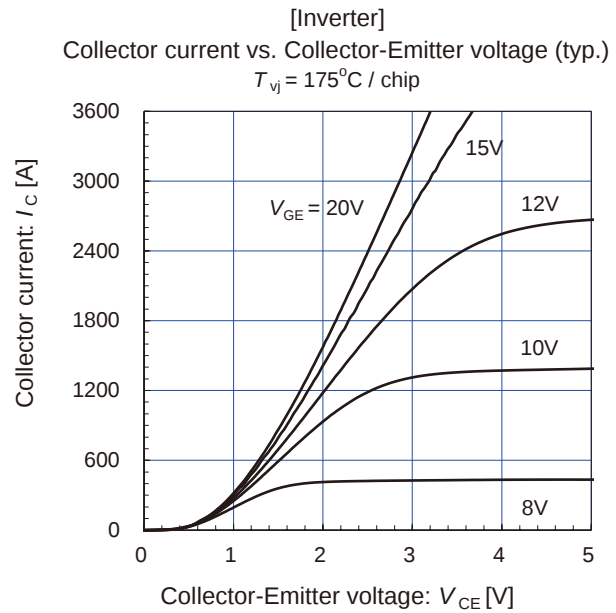
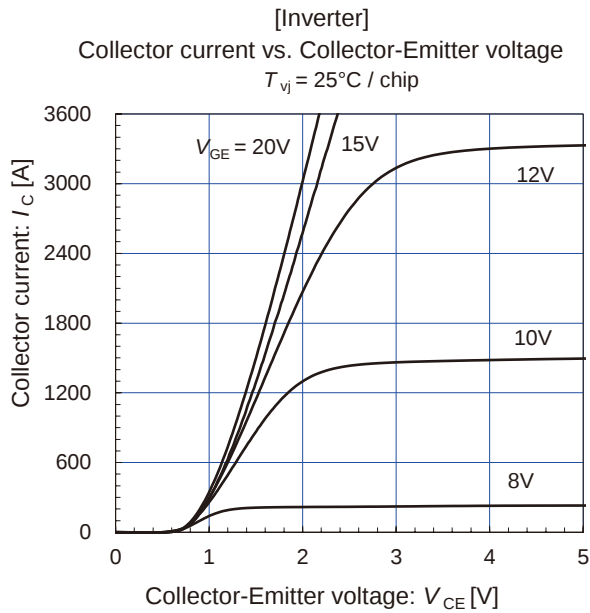
■ Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance junction to case(1 device)	$R_{th(j-c)}$	Inverter IGBT	-	-	11.5	K/kW
		Inverter FWD	-	-	22.0	
Thermal resistance case to heatsink(1 IGBT+1 FWD) (*1)	$R_{th(c-s)}$	with 1 W/(m·K) thermal grease	-	4.2	-	

(*1) This is the value which is defined mounting on the additional heatsink with thermal grease.

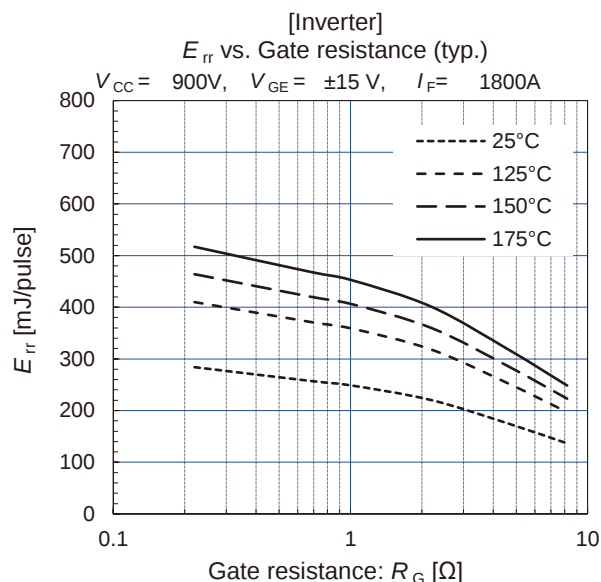
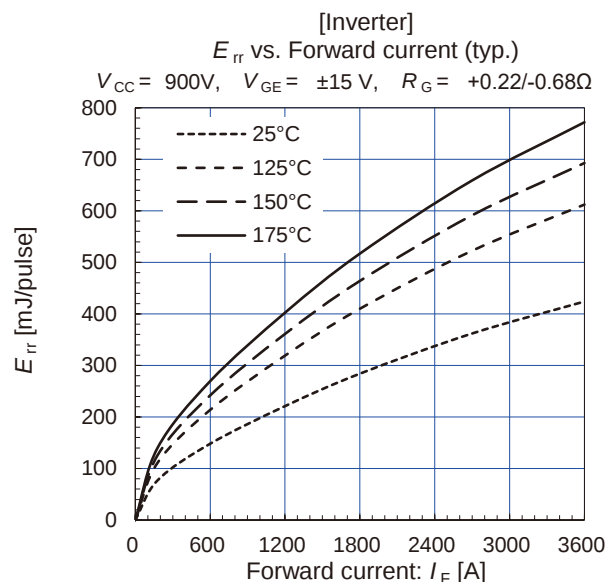
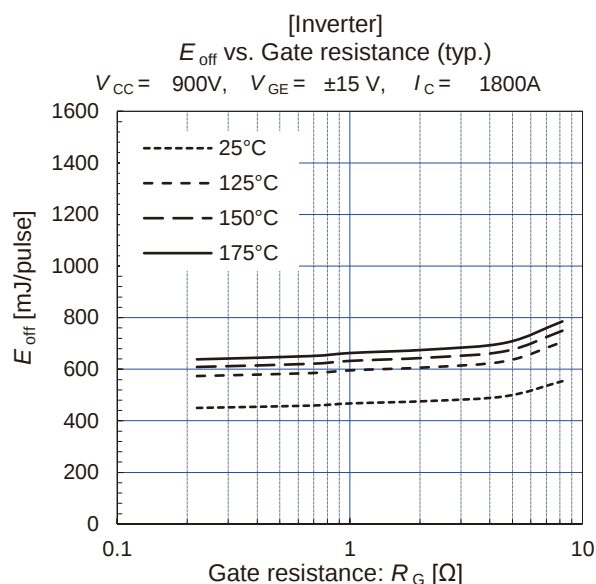
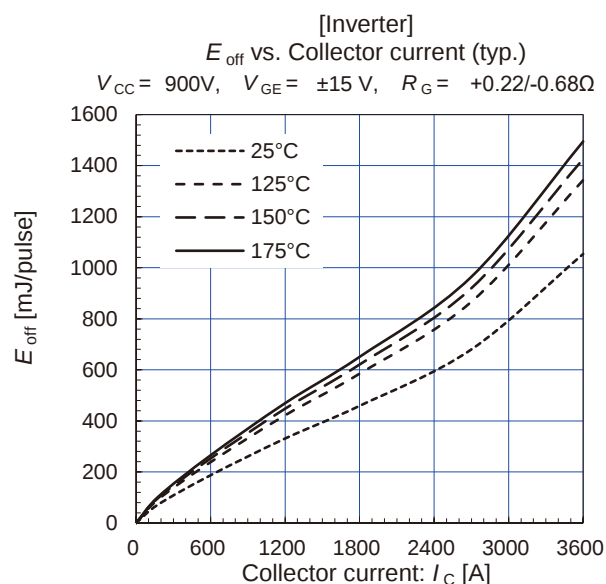
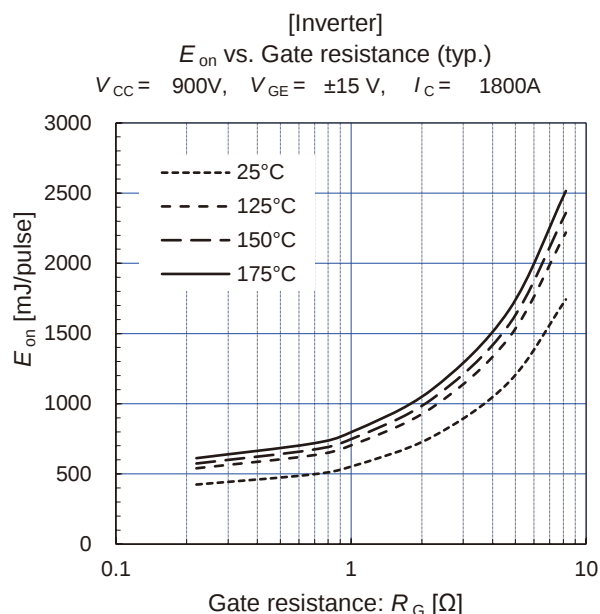
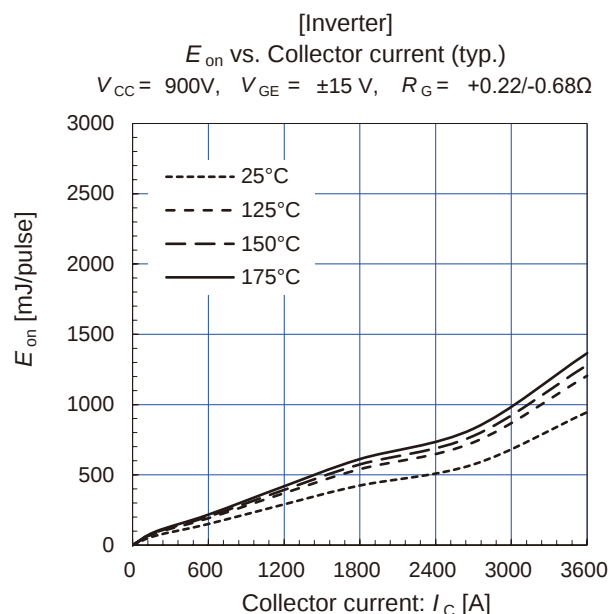
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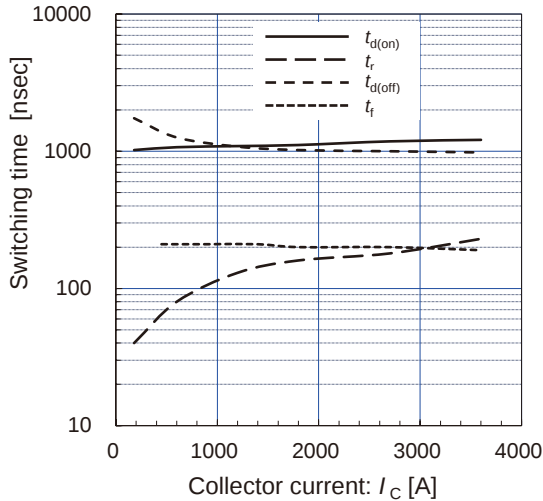
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[Inverter]

Switching time vs. Collector current (typ.)

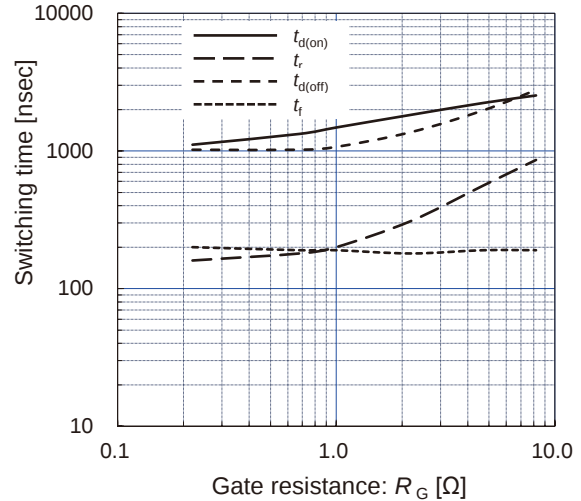
$V_{CC} = 900V$, $R_G = +0.22/-0.68\Omega$ $V_{GE} = \pm 15V$, $T_{vj} = 25^\circ C$



[Inverter]

Switching time vs. Gate resistance (typ.)

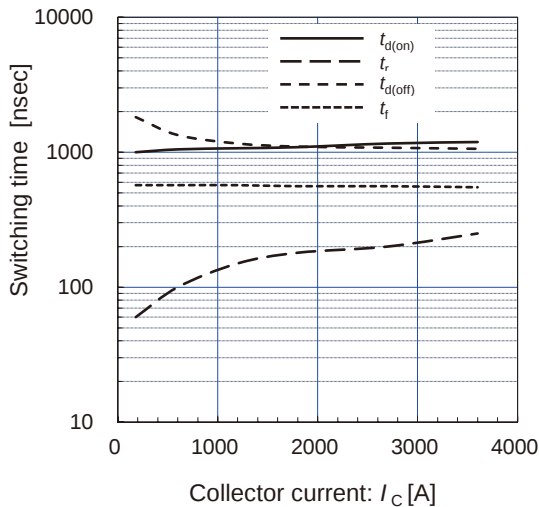
$V_{CC} = 900V$, $I_C = 1800A$, $V_{GE} = \pm 15V$, $T_{vj} = 25^\circ C$



[Inverter]

Switching time vs. Collector current (typ.)

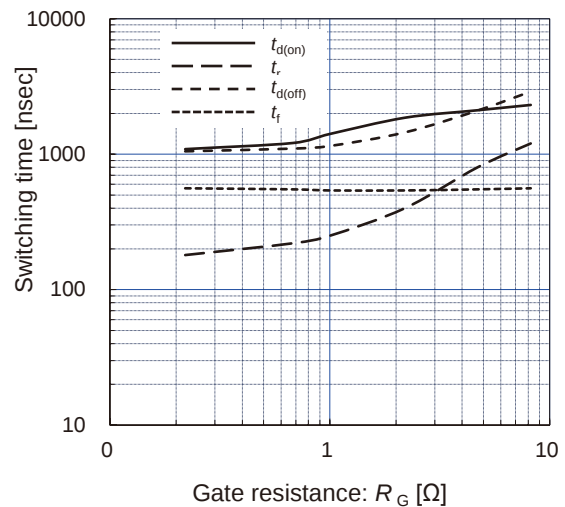
$V_{CC} = 900V$, $R_G = +0.22/-0.68\Omega$ $V_{GE} = \pm 15V$, $T_{vj} = 175^\circ C$



[Inverter]

Switching time vs. Gate resistance (typ.)

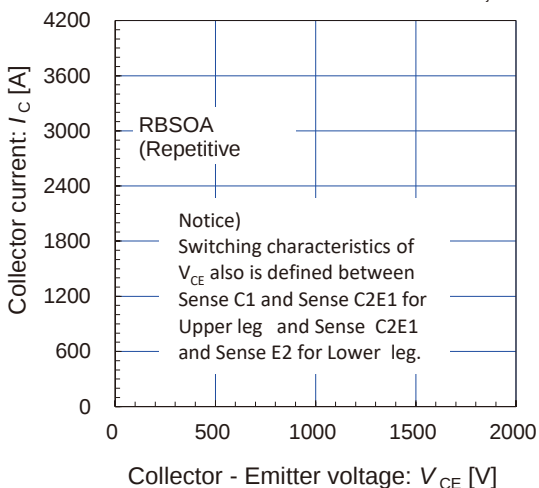
$V_{CC} = 900V$, $I_C = 1800A$, $V_{GE} = \pm 15V$, $T_{vj} = 175^\circ C$



[Inverter]

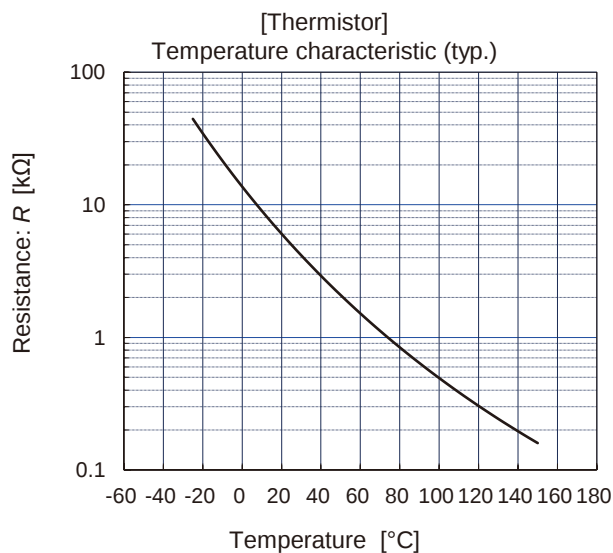
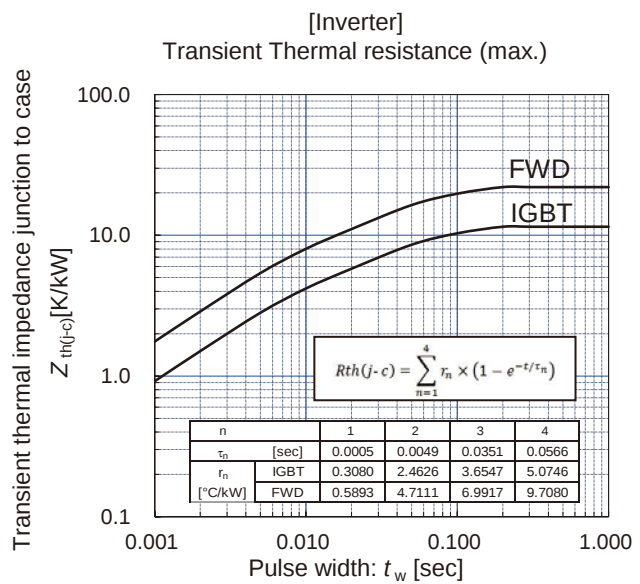
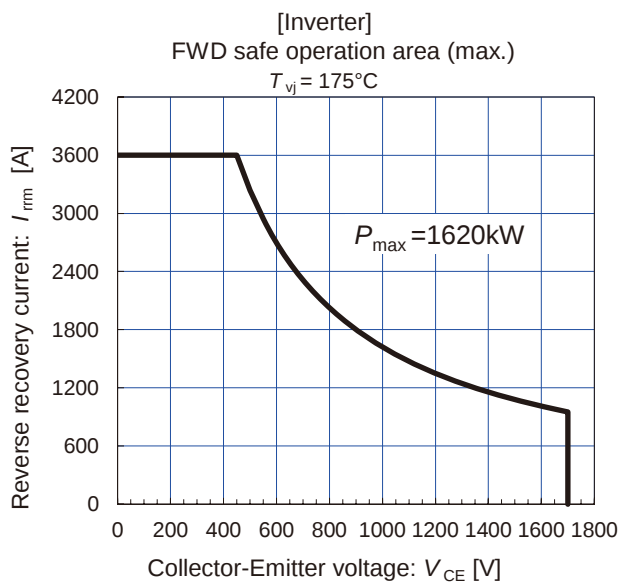
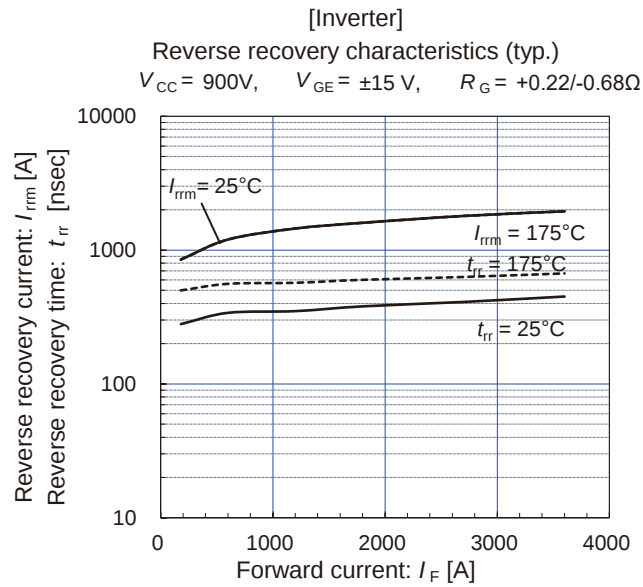
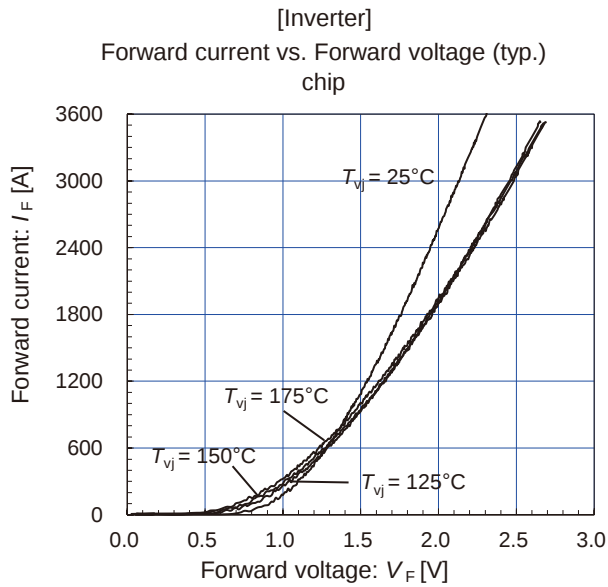
Reverse bias safe operating area (max.)

$V_{GE} = \pm 15V$, $R_G = +0.22/-0.68\Omega$ $T_{vj} = 175^\circ C$



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